

MOSFET - Power, Single N-Channel

40 V, 0.4 mΩ, 553.8 A

NTMTS0D4N04CL

Features

- Small Footprint (8x8 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Power Tools, Battery Operated Vacuums
- UAV/Drones, Material Handling
- BMS/Storage, Home Automation

MAXIMUM RATINGS (T_{.J} = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V_{DSS}	40	V
Gate-to-Source Voltage	9		V_{GS}	±20	V
Continuous Drain	Steady	T _C = 25°C	I _D	553.8	Α
Current R _{0JC} (Note 2)		T _C = 100°C	I _D	394.8	Α
Power Dissipation	State	T _C = 25°C	P_{D}	244	W
R _{θJC} (Note 2)		T _C = 100°C	P_{D}	122	W
Continuous Drain		T _A = 25°C	I _D	79.8	Α
Current R _{θJA} (Notes 1, 2)	Steady State	T _A = 100°C	I _D	56.4	Α
Power Dissipation R _{0JA} (Notes 1, 2)		T _A = 25°C	P_{D}	5.0	W
		T _A = 100°C	P_{D}	2.5	W
Pulsed Drain Current	$T_A = 25^{\circ}C, t_p = 10 \mu s$		I _{DM}	900	Α
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to + 175	°C
Source Current (Body Diode)			I _S	203.4	Α
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 70 A)			E _{AS}	4454	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		TL	260	°C	

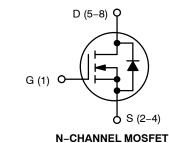
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

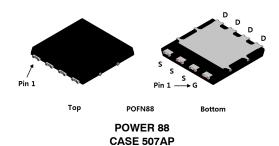
THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Note 2)	$R_{\theta JC}$	0.61	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	30.1	

^{1.} Surface-mounted on FR4 board using a 1 $\rm in^2$ pad size, 1 oz. Cu pad.

V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX	
40 V	0.4 mΩ @ 10 V	553.8 A	
40 V	0.64 mΩ @ 4.5 V		





MARKING DIAGRAM



XXX = Device Code (8 A-N characters max)

A = Assembly Location

WL = 2-digit Wafer Lot Code Y = Year Code

WW = Work Week Code

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

2. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

V mV/°C	
mV/°C	
μΑ	
nA	
V	
mV/°C	
, 0	
$m\Omega$	
S	
Ω	
pF	
	nC
 	
nC	
	V
- ns	
ns	
V	
ns	
ns	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$.

4. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS

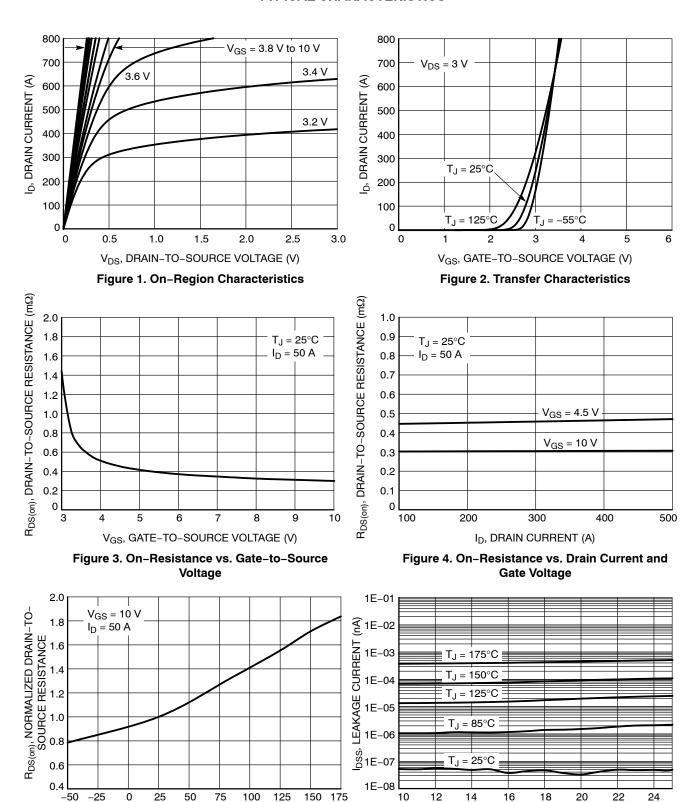


Figure 5. On–Resistance Variation with Temperature

T_J, JUNCTION TEMPERATURE (°C)

Figure 6. Drain-to-Source Leakage Current vs. Voltage

V_{DS}, DRAIN-TO-SOURCE VOLTAGE (V)

TYPICAL CHARACTERISTICS

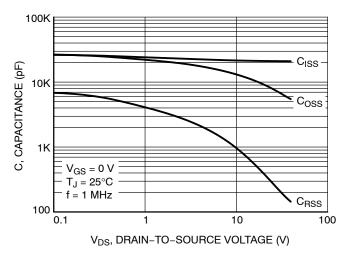


Figure 7. Capacitance Variation

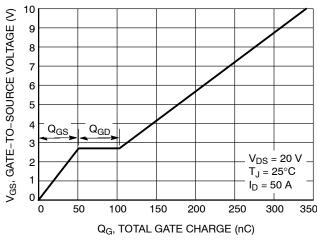


Figure 8. Gate-to-Source Voltage vs. Total Charge

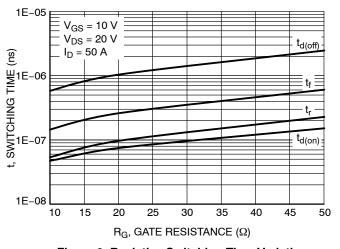


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

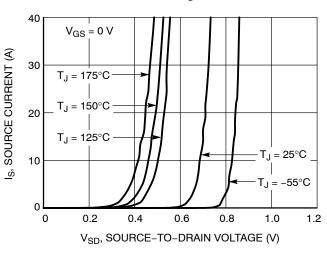


Figure 10. Diode Forward Voltage vs. Current

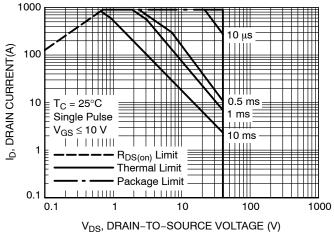


Figure 11. Maximum Rated Forward Biased Safe Operating Area

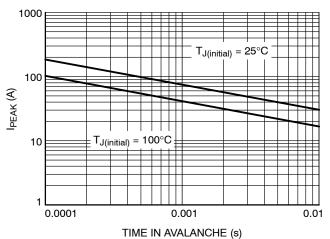


Figure 12. $I_{\mbox{\scriptsize PEAK}}$ vs. Time in Avalanche

TYPICAL CHARACTERISTICS

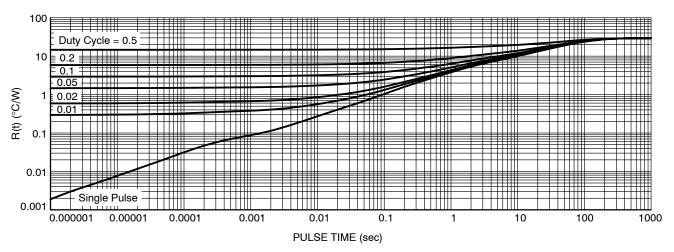


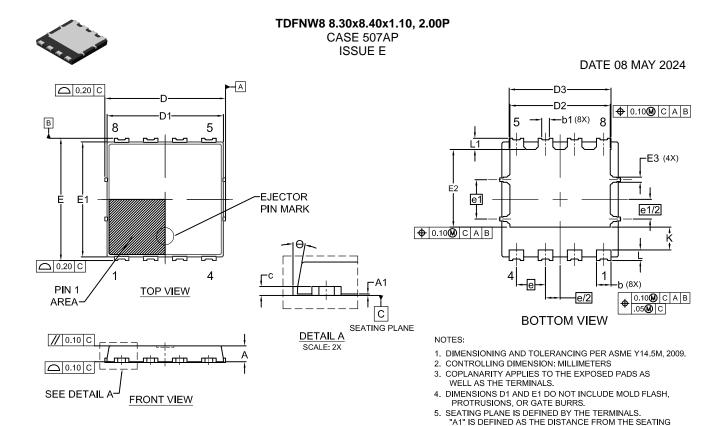
Figure 13. Thermal Characteristics

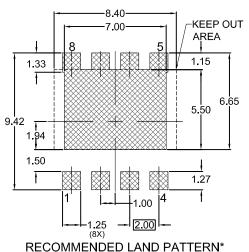
DEVICE ORDERING INFORMATION

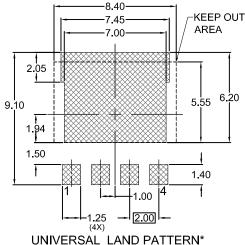
Device	Marking	Package	Shipping [†]
NTMTS0D4N04CLTXG	0D4N04CL	POWER 88 (Pb-Free)	TBD / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.









DIM	M	IILLIMET	ERS
Divi	MIN. NOM.		MAX.
Α	1.00	1.10	1.20
A1	0.00	-	0.05
b	0.90	1.00	1.10
b1	0.35	0.45	0.55
С	0.23	0.28	0.33
D	8.20	8.30	8.40
D1	7.90	8.00	8.10
D2	6.80	6.90	7.00
D3	6.90	7.00	7.10
Е	8.30	8.40	8.50
E1	7.80	7.90	8.00
E2	5.24	5.34	5.44
E3	0.25	0.35	0.45
е	2.00 BSC		
e/2	1.00 BSC		
e1	2.70 BSC		
e1/2	1.35 BSC		
K	1.50	1.57	1.70
Г	0.64	0.74	0.84
L1	0.67	0.77	0.87
θ	0°		12°

PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE	
STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOA	٩D
THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES	
REFERENCE MANUAL, SOLDERRM/D.	

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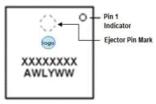
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TDFNW8 8.30x8.40x1.10, 2.00P

CASE 507AP ISSUE E

DATE 08 MAY 2024

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot Code
Y = Year Code
WW = Work Week Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

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